# **Tunable spin-phonon polarons in a chiral molecular qubit framework**

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## Abstract

Chiral structures that produce asymmetric spin-phonon coupling can theoretically generate spinphonon polarons—quasiparticles exhibiting non-degenerate spin states with phonon displacements. However, direct experimental evidence has been lacking. Using a chiral molecular qubit framework embedding stable semiquinone-like radicals, we report spin dynamic signatures that clearly indicate the formation of spin-phonon polarons for the first time. Our non-adiabatic model reveals that these quasiparticles introduce an active spin relaxation channel when polaron reorganization energy approaches Zeeman splitting. This new channel manifests as anomalous, temperature-independent spin relaxation, which can be suppressed by high magnetic fields or porefilling solvents (e.g. CH<sub>2</sub>Cl<sub>2</sub>, CS<sub>2</sub>). Such field- and guest-tunable relaxation is unattainable in conventional spin systems. Harnessing this mechanism could boost repetition rates in spin-based quantum information technologies without compromising coherence.

# Introduction

Chiral structures lack inversion and reflection symmetries. They exhibit reciprocity with electron spins: passing electrons through chiral biomolecules (1), polymers (2), and inorganic solids (3) could generate salient spin polarization, an effect called chirality-induced spin selectivity (4), and spin-polarized current could induce enantioselective electrochemical reactions (2). These intriguing phenomena have attracted great attention because they hold promise for new designs and methodologies towards high-performance spintronic devices (5), quantum information science (6), and asymmetric synthesis (7). Nonetheless, the underlying mechanism of the interplay between structural chirality and electron spin degree of freedom is still an open question (8). Recent theoretical studies indicate that chiral structures could cause asymmetric spin-phonon coupling, which infers the formation of spin-phonon polaron with energy splitting and phononic displacement between opposite spin states (9, 10). As spin-phonon coupling also drives spin relaxation and implicitly decoherence (11–13), this quasiparticle should exhibit peculiar spin dynamics, which remains unexplored both theoretically and experimentally.

To this end, molecular qubit frameworks (MQFs) provide a tunable platform to investigate the dynamics of spin-phonon polarons. MQFs integrate molecular electron spin qubits within open framework materials, such as metal-organic frameworks (*14*, *15*) and covalent organic frameworks (*16*). Their highly ordered crystal structures engender well-defined phonon dispersion relations, their bottom-up synthesis allows rational design of spin, phonon, and chirality characteristics, and their microporosity and high surface area further allow fine tuning of phonons by harnessing host-guest interactions (*17–19*). In addition, when stable organic radicals are used as qubits, MQFs could maintain quantum coherence at room temperature, enabling spin dynamic characterization across a wide range of temperature (3 K – 300 K) (*20–22*). This empowers investigation of spin-phonon coupling involving acoustic and optical phonons that stem from long-range structural features and local chemical bonds (*11*, *12*). Hence, MQFs with chiral structures and radical qubits could enable systematic examination of spin relaxation through rational structural design and phononic modulation.

Herein, we report spin dynamic signatures that clearly indicate the formation of spin-phonon polarons in a chiral and microporous MQF,  $Zn_3(HOTP)$  (HOTP = 2,3,6,7,10,11-hexaoxytriphenylene). Spontaneous oxidation of HOTP ligands generates semiquinone-like radical qubits with room-temperature electron spin coherence. They display a fast and nearly temperature-independent spin relaxation process at 0.34 T, which is suppressed by improving the

magnetic field or filling the pores with some organic solvents including dichloromethane (DCM), tetrahydrofuran (THF), and carbon disulfide (CS<sub>2</sub>). Considering that the chiral structure could induce asymmetric longitudinal spin-phonon coupling, we build up a non-adiabatic microscopic model that allows for the formation of spin-phonon polaron and solve it with polaron transformation as well as Fermi's golden rule similar to the manner of Marcus rate theory (23–26). This model shows that the anomalous and tunable spin relaxation of Zn<sub>3</sub>(HOTP) arise from an additional relaxation channel introduced by spin-phonon polarons, which is effective when the polaron reorganization energy approaches Zeeman splitting of different spin states.

### Results

### Chiral structure with incommensurate modulation

Zn<sub>3</sub>(HOTP) was synthesized via a solvothermal reaction between Zn(acetate)<sub>2</sub>·2H<sub>2</sub>O and 2,3,6,7,10,11-hexahydroxytriphenylene (HHTP), which yielded hexagonal rod-like crystals with longitudinal lengths of  $30 - 70 \,\mu\text{m}$  and cross-sectional lengths of  $1 - 2 \,\mu\text{m}$  (fig. S1). The product is crystalline, air-stable, and microporous with a Brunauer–Emmett–Teller surface area of 362 m<sup>2</sup>·g<sup>-1</sup> (fig. S2, S3) that is comparable with the previously reported value (27). Its structure remains intact in various organic solvents, e.g. DCM and *N*,*N*-dimethylformamide (DMF) (fig. S3). Individual single crystal of Zn<sub>3</sub>(HOTP) displays second harmonic generation (SHG) activity at 100 K and 295 K (fig. 1D), indicating spontaneous inversion symmetry breaking in this material (28).

Single-crystal structure of Zn<sub>3</sub>(HOTP) was characterized by continuous rotation electron diffraction (cRED) at 96 K and further refined by extended X-ray absorption fine structure (EXAFS) spectroscopy (fig. 1A, fig. S4 and S5, table S1 and S2). Based on the SHG activity of this framework, we solved its structure with non-centrosymmetric space groups and found that it crystalizes in P6<sub>3</sub>, a Sohncke space group, with a chiral structure (fig. 1F) (29). Zn<sub>3</sub>(HOTP) exhibits a honeycomb-like non-van-der-Waals three-dimensional (3D) framework with cylindrical pores whose diameters are approximately 1.6 nm (fig. 1E). HOTP ligands form eclipsed-stacked columns along the crystallographic c axis, which aligns with the long axis of single crystal as revealed by high-resolution transmission electron microscopy (HR-TEM), with an intermolecular distance of 3.305 Å (fig. 1C and E). These columns are connected via zigzag Zn-O ladders constructed by  $[Zn_2O_2]$  pseudo-squares where  $Zn^{2+}$  ions are not co-planar with HOTP ligands (fig. 1E). Each  $Zn^{2+}$  displays a trigonal bipyramidal coordination geometry with an axial water pointing into the pores (fig. 1E). Notably, Zn<sub>3</sub>(HOTP) is structurally and compositionally distinct from  $Zn_3(HOTP)_2$ , an alternative phase recently reported by Dincă et al (30). The latter, which is produced by a different synthetic procedure, consists of 4- and 5-coordinated Zn<sup>2+</sup> ions without coordinating water (30).

Electron diffraction of Zn<sub>3</sub>(HOTP) along the crystallographic *c* axis displays satellite reflections at 96 K (fig. 1A). Their periodicity is approximately 3.57 times of the corresponding unit cell parameter, yet it is irrational relative to the latter, characteristic of incommensurate modulation. Such structural aperiodicity is also observed in several other HOTP-based MOFs including Zn<sub>3</sub>(HOTP)<sub>2</sub> (*30*), La<sub>3</sub>(HOTP)<sub>2</sub>, and Nd<sub>3</sub>(HOTP)<sub>2</sub> (*31*). It reduces 6<sub>3</sub> screw axes to 3-fold rotation axes while retains structural chirality (fig. S6). Notably, Zn<sub>3</sub>(HOTP) transforms into a periodic structure at 295 K (fig. 1B), yet it still exhibits SHG activity (fig. 1D), showing that the chirality is intrinsic to this structure and is not a result of the incommensurate modulation. We employed Raman and Fourier-transform infrared (FT-IR) spectroscopy for  $Zn_3(HOTP)$  to investigate phonons near the Gamma point of 1<sup>st</sup> Brillouin zone. Vibrational peaks at 3420 cm<sup>-1</sup> and 699 cm<sup>-1</sup> are assigned to stretch modes of O–H and Zn–O bonds, respectively, and those at 1200 cm<sup>-1</sup> – 1600 cm<sup>-1</sup> are attributed to C–C and C–O stretches within HOTP (fig. 1G to I). Raman spectrum collected at 2 K and 0.34 T shows multiple peaks below 200 cm<sup>-1</sup> with the lowestfrequency peak is at 15 cm<sup>-1</sup> (fig. 1G). These low-frequency Raman features are well reproduced by calculations, indicating that they are inherent for the framework (fig. S7B). They pose the upper limit to Debye temperature (T<sub>D</sub> < 22 K), which indicates relatively low structural rigidity. A strong peak at 163 cm<sup>-1</sup> red-shifts to 151 cm<sup>-1</sup> for Zn<sub>3</sub>(HOTP) synthesized in D<sub>2</sub>O (fig. S7A), showing its stemming from hydrogen bonds formed between adsorbed H<sub>2</sub>O and HOTP or between adsorbed and coordinating H<sub>2</sub>O. As the electron spin of HOTP radical mainly resides on its oxygen atoms (22), vibrations of hydrogen bonds between HOTP and H<sub>2</sub>O, Zn–O bonds, and C–O bonds may contribute to local-mode spin relaxation of Zn<sub>3</sub>(HOTP).



Fig. 1. Structure and optical phonons of Zn<sub>3</sub>(HOTP). (A, B) cRED images in reciprocal space acquired at (A) 96 K and (B) 295 K. Red, green, and blue lines represent  $a^*$ ,  $b^*$ , and  $c^*$ , respectively. Main and satellite reflections are labeled. (C) HR-TEM image viewed perpendicular to crystallographic *c* axis. Bottom-left inset: Fourier transform of the HR-TEM image. Top-right

inset: HR-TEM image viewed along the crystallographic c axis. (**D**) SHG signals under 1064 nm pumping acquired at 100 K and 295 K. (**E**) Portions of the structure viewed along and perpendicular to the crystallographic c axis. Inset: coordination sphere of  $Zn^{2+}$ . Blue, grey, and red spheres represent Zn, C, and O, respectively. H atoms are omitted for clarity. (**F**) Left: Double-layer crystal packing showing structural chirality. Each circular plate represents a HOTP ligand and nearby secondary building units. They are marked with different colors to articulate the 6<sub>3</sub> screw-axis symmetry. Yellow and green arrows indicate clockwise and counterclockwise rotations corresponding to left and right handedness, respectively. Right: Chiral structures with left and right handedness in *P*6<sub>3</sub> space group viewed perpendicular to the crystallographic c axis. (**I**, **J**) Raman spectra collected at 2 K under 0.34 T. (**K**) FT-IR spectrum collected at 295 K under 0 T.

### Conventional polarons and spin coherence

We probed the spin characteristics of Zn<sub>3</sub>(HOTP) with continuous-wave electron paramagnetic resonance (CW-EPR) spectroscopy. The X-band (9.6 GHz, 0.34 T) CW-EPR spectrum acquired at 295 K reveals two types of S = 1/2 electron spins exhibiting Lorentzian line shape: one at g = 2.00341 with a linewidth of 0.40 mT and the other at g = 2.00237 with a linewidth of 2.37 mT (fig. 2A). Both *g*-factors are close to the free-electron value ( $g_e = 2.0023$ ) and consistent with radical characteristics. As the temperature rises from 130 K to 295 K, the double integration, which is proportional to magnetic susceptibility ( $\chi$ ), of the first type drops significantly (fig. 2B and C). This is consistent with Curie-like paramagnetism (32, 33). In contrast, the second type displays nearly temperature-independent paramagnetism (TIP). Q-band (34 GHz, 1.22 T) and millimeterwave (214 GHz, 7.64 T) CW-EPR spectra acquired at 295 K can be fitted using one type of electron spin with a slight *g*-anisotropy ( $g_{\parallel} = 2.00046$  and  $g_{\perp} = 2.00218$ ) and narrow linewidth (fig. S8). The TIP-type electron spin is absent at high magnetic field, consistent with field-induced suppression of TIP observed in magnetometry (fig. S9).

The drastically different linewidths and paramagnetic properties of the two types of electron spins suggest their distinct physical origins. These behaviors are comparable with previous observations of doped polyaniline (*32*) and fully reduced Cu<sub>3</sub>(C<sub>6</sub>O<sub>6</sub>)<sub>2</sub> (H<sub>4</sub>C<sub>6</sub>O<sub>6</sub> = tetrahydroxy-1,4-benzoquinone) (*33*). Accordingly, we assign the TIP-type spins to large (Fröhlich) polarons that originate from coupling between delocalized electrons and phonons (*32–34*). Their formation is facilitated by the  $\pi$ – $\pi$  stacking between HOTP ligands, consistent with the relatively high pressed-pellet electrical conductivity of Zn<sub>3</sub>(HOTP) at 295 K ( $\sigma$  = 3.35 × 10<sup>-5</sup> S·cm<sup>-1</sup>; fig. S10). On the other hand, the Curie-like spins are attributed to small (Holstein) polarons residing at localized defects (*33, 34*), i.e. semiquinone-like radicals formed from spontaneous oxidation of HOTP in the air. Quantitative CW EPR analysis revealed that approximately 1% of HOTP ligands form small polarons (Table. S3).

Our previous studies have shown that localized HOTP radicals in MQFs behave as electron spin qubits with room-temperature quantum coherence (15, 22). This prompted us to investigate the spin dynamics of Zn<sub>3</sub>(HOTP) and to explore its potential as an MQF with X-band pulse EPR spectroscopy. At both 100 K and room temperature, the echo-detected field sweep spectra display single peaks with Gaussian line widths of approximately 0.51 mT (fig. S11). Hence, only the small polarons can be probed by pulse EPR spectroscopy, whereas the large polarons lose coherence so fast that they are not measurable. Nutation experiments conducted at 295 K revealed Rabi oscillations, demonstrating coherent addressability (fig. S12). The phase memory time ( $T_m$ ), which represents the spin decoherence time ( $T_2$ ) for ensemble systems, is approximately 700 ns at 13 K.

It increases to 1.01  $\mu$ s at 63 K and gradually decreases to 376 ns at 295 K (fig. 2D). Overall, the small polarons of Zn<sub>3</sub>(HOTP) behave as room-temperature electron spin qubits, qualifying this material as an MQF.



**Fig. 2. CW-EPR spectra of Zn<sub>3</sub>(HOTP).** (**A**) CW-EPR spectrum collected at X-band and 295 K and associated fitting results. (**B**) CW-EPR spectra collected at X-band from 130 K to 290 K. (**C**) EPR area  $\times$  T (proportional to  $\chi$ T) vs temperature (T) data for large and small polarons. (**D**)  $T_1$  and  $T_m$  of small polarons collected at X-band from 13 K to 295 K.

#### Anomalous and tunable spin relaxation of small polarons

Zn<sub>3</sub>(HOTP) exhibits exceptionally short spin relaxation time ( $T_1$ ) at X-band with weak temperature dependence from 13 K to 295 K.  $T_1$  is 31.9 µs at 13 K, which is shorter than the value of another HOTP-based MQF, TiHOTP, at the same temperature by 3 orders of magnitude (22). It gradually decreases as the temperature rises, reaching nearly 10 µs at 295 K (fig. 2D). This spin relaxation behavior differs from all other stable organic radical qubits (11, 21). To articulate spin relaxation mechanisms of Zn<sub>3</sub>(HOTP), we further acquired its  $T_1$  at various temperatures with Q-band (1.22 T, 34 GHz) and W-band (3.34 T, 94 GHz) pulse EPR spectroscopy (fig. 3A and B). Raising the magnetic field significantly suppresses spin relaxation below 100 K and induces a significant temperature dependence of  $T_1$  (fig. 3C). Specifically,  $T_1$  became 3.39 ms and 1.59 ms at 13 K under 1.22 T and 3.34 T, respectively, both of which are nearly two orders of magnitude longer than the value observed under 0.34 T. The spin relaxation rates ( $1/T_1$ ) collected at Q-band and W-band exhibit comparable temperature dependencies above 18 K, yet they diverge below this temperature with  $T_1$  being slightly shorter under higher magnetic field. This comparison indicates contributions of a field-dependent direct process and field-independent two-phonon (Raman and

local-mode) relaxation processes to the spin relaxation in  $Zn_3(HOTP)$  at Q-band and W-band (12, 22).

Based on these results, we tentatively analyzed spin relaxation mechanisms of  $Zn_3(HOTP)$  with the following equation:

where the three terms describe a temperature-independent spin relaxation process, the direct process, and local-mode processes. C is a constant; v, k<sub>B</sub>, and T represent linear vibrational frequency, Boltzmann constant, and temperature. A<sub>Dir</sub> and A<sub>Loc</sub> are pre-factors of direct and local-mode processes, respectively. Fitting the temperature dependence of  $1/T_1$  reveals that the spin relaxation at X-band involves a temperature-independent process and a local-mode process driven by the vibration of hydrogen bonds (v/c = 163 cm<sup>-1</sup>; c represents the speed of light; fig. S13). The former is dominant below 170 K with an exceptionally high rate (C =  $4.5 \times 10^4$  s<sup>-1</sup>) that indicates a fast spin relaxation, and the latter causes a slight decrease of  $T_1$  towards room temperature. At Q-band and W-band, the direct process plays a major role below 50 K, and local-mode processes driven by vibrations of hydrogen bonds and Zn–O bonds (v/c = 699 cm<sup>-1</sup>) dominate at higher temperatures (fig. 3E and F). Notably, the temperature-independent process is quenched at these magnetic fields, indicating that this process is field-tunable and sensitive to the electronic Zeeman splitting of small polarons (fig. 3B).



Fig. 3. Magnetic field modulation of spin relaxation. (A) Schematic diagram of a sample of Zn<sub>3</sub>(HOTP) crystallites in an EPR spectrometer. B<sub>0</sub> represents a static magnetic field and B<sub>1</sub> a microwave magnetic field. (B) Zeeman splitting of small polarons in Zn<sub>3</sub>(HOTP). Magnetic fields and corresponding microwave frequencies used in experiments are indicated. The red sphere with an arrow represents an electron spin. E represents energy.  $\alpha$  and  $\beta$  represent different spin states. (C) Temperature dependence of  $1/T_1$  for Zn<sub>3</sub>(HOTP) powders acquired at X-band (0.34 T), Q-

band (1.22 T), and W-band (3.34 T). (**D**–**F**) Spin relaxation mechanisms of  $Zn_3(HOTP)$  powders at (D) X-band, (E) Q-band, (F) W-band. Dash lines labeled as "Thermal" and " $\nu/c$ " represent thermally activated and local-mode processes, respectively.

We further probed the influence of phonons on the spin relaxation in  $Zn_3(HOTP)$  by immersing this material in various organic solvents while measuring its  $T_1$  at X-band (the sample is named as  $Zn_3(HOTP)@$ solvent). The immersion enforces adsorption of solvent molecules into the nanoscale pores of  $Zn_3(HOTP)$  (fig. 4A), which could tweak phonon dispersions through host-guest interactions (18). When  $Zn_3(HOTP)$  is immersed in DCM, THF, and  $CS_2$ , its  $T_1$  becomes significantly longer below 100 K and exhibits a strong temperature dependence (fig. 4B). The spin relaxation involves a direct process and local-mode processes driven by vibrations of hydrogen bonds and Zn–O bonds, whereas the temperature-independent process is quenched (fig. 4D and fig. S14).

Distinct from the above observation, when  $Zn_3(HOTP)$  is immersed in DMF, *N*,*N*-diethylformamide (DEF), *N*,*N*-dimethylacedamide (DMAc), and dimethoxyethane (DME), its  $T_1$  becomes slightly longer while remaining nearly temperature-independent below 110 K, and it decreases acutely above this temperature (fig. 4C). Whereas the temperature-independent process persists with a slightly lower rate, the local-mode process becomes mainly driven by the stretch mode of Zn–O bond (fig. S15). The vibration of hydrogen bonds contributes negligibly to spin relaxation, indicating that these hydrogen-accepting and water-miscible solvents tend to disrupt hydrogen bonds between the adsorbed H<sub>2</sub>O and HOTP radicals by replacing the former in the pores. These observations demonstrate subtle tunability of phonons in Zn<sub>3</sub>(HOTP) with guest molecules. Such phononic modularity is typically unfeasible for dense inorganic solids as their phonon dispersion relations are determined by crystal structures (*35*), yet it is easily achievable for microporous materials by harnessing host-guest interactions.

Notably, although  $T_1$  of Zn<sub>3</sub>(HOTP) powders at X-band is much shorter than those under higher magnetic fields or soaked in DCM, THF, and  $CS_2$ ,  $T_m$  of these samples are comparable, indicating that spin decoherence is not governed by relaxation for this material (fig. S16). Hence, the temperature-independent process can be harnessed to improve repetition rates of quantum operations for quantum information technologies while maintaining the qubit coherence (36, 37). Typically, quantum operations need to be repeated many times, where qubits should be reset to thermal equilibrium at the beginning of each repetition (35). Accordingly, the time required for each repetition should well exceed five times of  $T_1$  to reach more than 99% relaxation (38), which often leads to compromise between experimental time and signal-to-noise ratio (SNR). To demonstrate this point, we conducted dynamical decoupling for  $Zn_3(HOTP)$  powders ( $T_m = 750$ ns) and Zn<sub>3</sub>(HOTP)@DCM ( $T_m = 690$  ns) at X-band and 30 K with a Carr-Purcell-Meiboom-Gill (CPMG) pulse sequence consisting of 6 spin-locking  $\pi$  pulses. The CPMG sequence improved  $T_{\rm m}$ of these samples to 2.16 µs and 1.65 µs, respectively. Nonetheless, the corresponding measurements took 20 min and 180 min, respectively, under the same experimental parameters except for the repetition time (fig. 4F). Thus, the temperature-independent process facilitates spin relaxation without deteriorating coherence in  $Zn_3(HOTP)$ , which helps enhance the repetition rate for dynamical decoupling by 9 times.



**Fig. 4. Guest modulation of spin relaxation.** (A) Schematic diagram of  $Zn_3(HOTP)$  crystallites soaked in solvents. Solvent molecules are adsorbed into pores. (B) Temperature dependence of  $1/T_1$  for  $Zn_3(HOTP)$  soaked in DCM, THF, and CS<sub>2</sub> acquired at X-band. (C) Temperature dependence of  $1/T_1$  of  $Zn_3(HOTP)$  soaked in DMF, DEF, DMAc, and DME acquired at X-band. (D, E) Spin relaxation mechanisms of  $Zn_3(HOTP)$  soaked in (D) DCM and (E) DMF at X-band. Dash lines labeled as "Thermal" and " $\nu/c$ " represent thermally activated and local-mode processes, respectively. (F) CPMG echo decay traces for  $Zn_3(HOTP)$  powders and  $Zn_3(HOTP)@DCM$  collected at X-band and 30 K. Sharp spikes are electron spin echo envelope modulation signals.

#### Analysis of spin relaxation mechanism

The efficient and temperature-independent spin relaxation in the powder of Zn<sub>3</sub>(HOTP) at X-band is rarely observed for electron spin systems. This anomalous behavior cannot be rationalized by common molecular spin relaxation mechanisms including direct, Raman, Orbach, and local-mode processes, whose scaling factors are equal to or above 1 in our experimental temperature range (11, 12). Tumbling-induced spin relaxation is irrelevant as HOTP radicals are fixed by the lattice and cannot freely tumble. To our knowledge, similar phenomenon has only been analyzed for nanomagnets as well as heavily doped insulators and semiconductors, where it is attributed to quantum tunneling of magnetization (QTM) (39), cross relaxation between localized spins (40, 41), or mutual scattering between mobile and localized electrons (42-44). Nonetheless, our experimental results rule out these mechanisms for Zn<sub>3</sub>(HOTP). First, QTM takes place between degenerate spin states (39), yet HOTP radicals possess non-degenerate spin states under external magnetic field due to Zeeman splitting. Second, the adsorption of DCM in Zn<sub>3</sub>(HOTP) significantly suppresses its temperature-independent spin relaxation. However, DCM should not change the spin density, charge density, or charge mobility of Zn<sub>3</sub>(HOTP) as it is redox-innocent and it does not alter the crystal structure of the framework (fig. S3). Accordingly, its adsorption should not modulate spin-spin interaction (cross relaxation) or mutual scattering between mobile and localized electrons, excluding these two mechanisms. In addition, common semiconductor spin relaxation mechanisms, e.g. Elliot-Yafet mechanism, D'yakonov-Perl' mechanism, Bir-Aronov-Pikus mechanism, etc., are not applicable because they are derived for delocalized electrons rather than small polarons (45, 46).

As the adsorption of DCM could subtly tweak phonons of  $Zn_3(HOTP)$  through host-guest interactions, the seemingly temperature-independent spin relaxation likely stems from spinphonon coupling. Indeed, it is consistent with the thermally activated process where  $T_1$  could be temperature-independent when the activation energy barrier (E<sub>a</sub>, in the unit of temperature) is much lower than the lowest experimental temperature. Hence, we revised Equation 1 as follows:

Here, A<sub>Therm</sub>,  $\tau_c$ , and  $\omega$  represent the pre-factor, correlation time, and electron spin Larmor frequency of the thermally activated process, respectively, with  $\tau_c = \tau_c^0 \exp(E_a/k_BT)$  where  $\tau_c^0$ is a preexponential factor (11). Fitting the temperature dependence of  $T_1$  with Equation 2 revealed  $E_a$  of 5 K for Zn<sub>3</sub>(HOTP) powder at 0.34 T, which drops to 2 K upon soaking in DMF, DEF, and DME (fig. 3D and fig. 4E; fig. S17, table S16). Although a low-barrier thermally activated process could account for the experimental data, its underlying microscopic mechanism remains unclear. Key questions persist: what is the nature of the barrier-crossing event? Why is the spin relaxation rate sensitive to both magnetic fields and pore-filling solvents? A new mechanism is demanded to explain the anomalous spin relaxation behavior of Zn<sub>3</sub>(HOTP).

#### Spin-phonon polarons

Motivated by the intrinsic structural chirality as well as the unique field- and guest-tunable spin relaxation behaviors of  $Zn_3(HOTP)$ , we introduce an additional relaxation channel assisted by spin-phonon polarons, which is described by the following nonadiabatic microscopic model:

Here,  $\hat{\sigma}_z$  and  $\hat{\sigma}_x$  are Pauli matrices;  $\alpha_1$ ,  $\alpha_2$ , and  $\gamma_1$  are spin-phonon coupling constants. The coupling constant  $\gamma_1$  is proportional to the external magnetic field strength (*B*) originated from the vibrational dependence of the Landé *g*-factor (47, 48). The four terms describe the electronic Zeeman splitting, lattice phonon bath, linear and quadratic transverse spin-phonon coupling, as well as longitudinal spin-phonon (polaron-like) interaction, respectively. The spin system with Zeeman splitting  $\Delta$  couples with two bands of phonons: the collective mode  $\hat{Q}_{sl}$  drives conventional spin-lattice relaxation, e.g. direct, Raman, and local-mode processes, while an additional mode  $\hat{Q}_{sp}$  asymmetrically couples with different spin states, enabling the formation of a spin-phonon (fig. 5A). Notice that the polaron displacement is proportional to  $\gamma_1$ , which is again proportional to *B*, and that the sign of  $\gamma_1$  reflects the handedness of the chirality (9, 49).

A straightforward Fermi's Golden Rule calculation (see Supplementary Materials) indicates that the spin-phonon polaron modulates the spin relaxation rate with a factor of  $\exp\left[-\frac{(\Delta - E_r)^2}{4k_BTE_r}\right]$ , analogous to the Marcus theory (50). The reorganization energy  $E_r$  depends on both the phonon spectral density and B. In particular,  $E_r$  shows a strong field dependence as  $E_r \propto \gamma_1^2 \propto B^2$ . In the high-temperature limit, the quantum Fermi's Golden Rule reduces to a classical thermally activated transition with  $E_a = (\Delta - E_r)^2/4E_r$ , indicating that the thermally activated spin relaxation process is a natural consequence of the spin-phonon polaron-assisted relaxation. Notably, the spin-phonon polaron modulation is independent of the structural chirality as  $E_r$  is quadratic to  $\gamma_1$ . As a result, this mechanism is applicable to the racemate of Zn<sub>3</sub>(HOTP) used in the experiments.

This microscopic model explains the abovementioned fast and nearly temperature-independent spin relaxation. As the magnetic field increases, both  $\Delta$  and spin-phonon polaron displacement scale with *B* linearly, whereas  $E_r$  is quadratic to *B* (fig. 5B). At lower magnetic fields, the spin-state transitions are more accessible because little thermal fluctuation is required to reach the potential crossing. As a result, the spin-phonon polaron-assisted relaxation channel is open and dominant, leading to efficient spin relaxation with weak temperature dependence (see Supplementary Materials). This is likely the situation for Zn<sub>3</sub>(HOTP) powders and those soaked in DMF, DEF, DMAc, and DME at X-band. The temperature dependencies of  $T_1$  observed for these samples can be well fitted by the rate function derived from Equation 3 (fig. 5C and D; fig. S18).

This model also explains the field- and guest-induced suppression of the above spin relaxation behavior. Raising the magnetic field from 0.34 T to 1.22 T (or 3.34 T) raises  $E_r$ . Changing guest molecules in the pores might alter the vibrational environment around the radical, which varies the spin-phonon coupling strength and density of states thereby enhancing  $E_r$ . In either case,  $E_r$  could become too large to be overcome by thermal fluctuations, effectively suppressing the spin-phonon polaron-assisted relaxation channel. As a result, the conventional direct and local-mode processes dominate the relaxation dynamics. This is likely the situation for  $Zn_3(HOTP)$  powders at Q- and W-band as well as those soaked in DCM, THF, and CS<sub>2</sub> at X-band. The temperature dependencies of  $T_1$  observed for these samples can be successfully fitted using the standard rate expressions for conventional spin relaxation mechanisms (fig. 3E and F; fig. 4D; fig. S14).



Fig. 5. Spin-phonon polaron-assisted spin relaxation. (A) Potential energy surfaces of different spin states ( $|0\rangle$  and  $|1\rangle$ ) of a S = 1/2 system as a function of polaron distortion coordinate  $\hat{Q}_{sp}$ . (B)

Mechanism for the magnetic-field-controlled activation and suppression of the spin-phonon polaron-assisted relaxation channel. (**C**, **D**) Fitting of the temperature dependence of spin relaxation rates for (C)  $Zn_3(HOTP)$  powders and (D)  $Zn_3(HOTP)@DMF$  acquired at X-band based on rate functions derived from Equation 3 (see Supplementary Materials).

## **Conclusions**

Our studies reveal experimental evidence of spin-phonon polarons for the first time in a chiral and microporous MQF, Zn<sub>3</sub>(HOTP). They likely emerge from chirality-induced asymmetric spin-phonon coupling and cause anomalous and tunable spin relaxation behaviors by introducing an additional relaxation channel. As a result, the seemingly unexpected temperature-independent feature of spin relaxation rate can be then explained by the existence of barrierless spin-phonon polaron state. The presence of these quasiparticles should not be limited to MQFs—they should be able to form in chiral polymers, soft inorganic solids (e.g. chiral halide perovskites), and artificial structures under appropriate magnetic fields. Further investigations of their dynamics and their influence on electron (or spin) transport could reveal insights into the interplay between structural chirality and electron spin degree of freedom. In addition, spin-phonon polarons could facilitate relaxation while maintaining coherence for electron spin qubits, which might occur in solid-state defects and semiconductor quantum dot qubits as well. Harnessing this unique property could shorten the time needed for qubit initialization thereby improving repetition rates in quantum operations, leading to new strategies for high-efficiency spin-based quantum computing and quantum sensing.

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### Acknowledgements

A.Z. and L.S. acknowledge Dr. Fushan Geng and Prof. Bingwen Hu for assistance with Q-band EPR spectroscopy, Zengwen Wang and Prof. Zhenxing Wang for assistance with preliminary millimeter-wave EPR experiments, and Yingchao Wang for assistance with electrical characterization. A.Z. thanks Dr. Qike Jiang, Danyu Gu, Dr. Xiaohe Miao, Dr. Zhong Chen, Zhongwei Yang, Yunlong Fan, and Tongyang Zhao for assistance with material characterization. A.Z. and L.S. thank the Instrumentation and Service Center for Molecular Sciences and the Instrumentation and Service Center for Physical Sciences at Westlake University for facility support and technical assistance. A. Z. and L.S. thank Dr. Zhongyue Zhang, Prof. Congjun Wu, Prof. Shen Zhou, Jiayi Huang, and Prof. Hongfei Wang for helpful discussions. R.B. and W.D. acknowledge the helpful discussions with Prof. Yijing Yan.

**Funding:** This work was supported by the National Natural Science Foundation of China (No. 22273078, No. 22361142829, No. 22371121), Zhejiang Provincial Natural Science Foundation (No. XHD24B0301), the Hangzhou Municipal Funding Team of Innovation (TD2022004), and Scientific Research Project of Westlake University (No. WU2024B025). A portion of this work was carried out at the Synergetic Extreme Condition User Facility (SECUF, https://cstr.cn/31123.02.SECUF), the Electron Spin Resonance System at the Steady High Magnetic Field Facility, CAS (https://cstr.cn/31125.02.SHMFF), and the 17B beamline of Shanghai Synchrotron Radiation Facility (SSRF). T.R. was supported by the College of Liberal Art and Sciences at Arizona State University. Work in the Dincă group was funded by the Department of Energy, Basic Energy Sciences (DE-SC0023288). Computational resources were provided by the Westlake HPC Center.

**Author contributions:** L.S., W.D., A.Z., and R.B. conceived the idea, designed experiments, and oversaw the project. A.Z. conducted material synthesis, EPR characterization, and vibrational spectroscopy. R.B. performed theoretical analysis. Z.Z., X.T., and J.L. conducted structural determination. L.Y, M.D., performed preliminary synthesis and material characterization. D.L. and S.L. conducted phonon DOS calculation. M.T. and F.J. assisted with Raman spectroscopy. W.N. assisted with dynamical decoupling experiments. H.S. performed magnetometry. J.G. and J.D. assisted with TEM imaging and structural analysis. X.Z. and Z.S. assisted with W-band EPR spectroscopy. Z.Z. and W.T. performed millimeter-wave EPR spectroscopy. T.R. performed preliminary X-band EPR characterization. L.S., W.D., A.Z., and R.B. co-wrote the manuscript. All authors have given approval to the final version of the manuscript.

**Competing Interests:** The authors declare that they have no competing interests.

**Data and materials availability:** All data are available in the main text and the supplementary materials.

### **Supplementary Materials**

Materials and Methods Supplementary text Figs. S1 to S28 Tables S1 to S16 References (31)